The Role of Crystal Structure – II

(Miller Indices)

Content

- ✓ Significance of crystallographic direction and plane
- ✓ Miller indices
- ✓ Linear & Planar density

Significance of Crystallographic directions and planes

- ✓ Deformation under loading (eg. slip) occurs on certain crystalline planes and in certain crystallographic directions.
- ✓ Helps to predict modes of material failure.
- ✓ Other properties of materials (electrical conductivity, thermal conductivity, elastic modulus, magnetic property, piezoelectric property etc.) can vary in a crystal with orientation.

Example



Efficient strong Ni based single crystal turbine blades withstand high temperature due to absence of grain boundaries because blades are grown on close packed direction [1 1 0] FCC Ni.

http://www.gwggggggg

Image: http://www.swansea.ac.uk/

GaAs lasers in CD players are grown from GaAs single crystals grown along [1 0 0] direction.



CD player laser



Computer chips come from Si wafers sliced from single crystal Si grown along [1 0 0] direction.

Silicon ingots and wafers in various sizes

Image: http://www.chipsetc.com/



Miller Indices

- Miller Indices are the designation of the planes and direction in the unit cell.
- The number of indices will match with the dimension of the lattice or the crystal. Example: In 3-D, unit cell has 3 indices namely (h k l).
- (h, k, l) represents a point but "no comma" is used while representing indices.

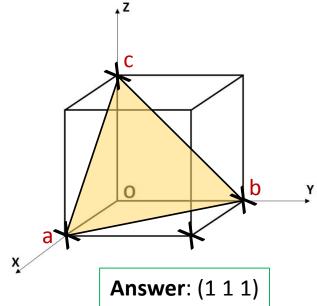
Meaning of the different brackets

Name	Symbol	Meaning
Half-moon Bracket	()	Individual Plane - (1 0 0)
Curly Bracket	{ }	Family of Planes {1 0 0} = (1 0 0), (0 1 0), (0 0 1)
Square bracket	[]	Individual direction - [1 0 0]
Carrot Bracket	< >	Family of Directions
		<1 0 0> = [1 0 0], [0 1 0], [0 0 1]

How to find Miller Indices of a given plane?

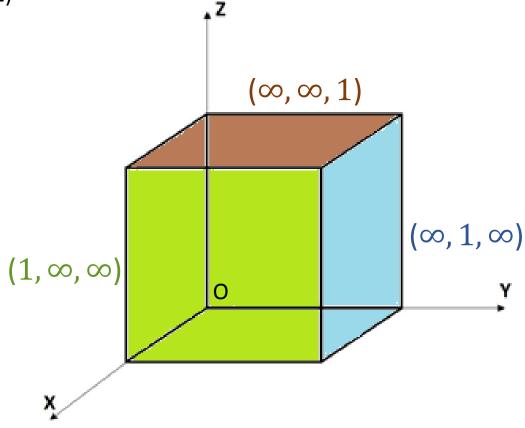
Steps involved

- > Choose origin O in unit cell such that
 - ✓ Plane does not touch the origin.
 - ✓ Plane is closest to the origin.
- Mark intercepts from chosen origin O along X-axis as 'a', from O along Y-axis as 'b' and from O along Z-axis as 'c'.
- > Take reciprocal of the intercepts, i.e., 1/a, 1/b, 1/c.
- Modify the reciprocal
 - ✓ Reduce multiples.
 - ✓ Fliminate fraction
 - ✓ Put bar above the negative integer in indices (if any)
 - ✓ Place round bracket around indices (no commas)



Thus, Miller Indices (h j k) are the reciprocals of the parameters (l, m, n) of each crystal face.

- Green Face = $(1/1, 1/\infty, 1/\infty) = (1 \ 0 \ 0)$
- Brown Face = $(1/\infty, 1/\infty, 1/1) = (0 \ 0 \ 1)$
- Blue Face = $(1/\infty, 1/1, 1/\infty) = (0\ 1\ 0)$

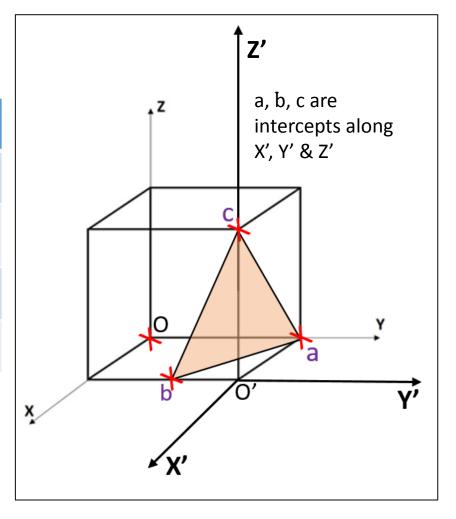




Determine the indices for the given plane.

- Plane cannot touch origin
- Choose closest origin

1.Choose new Origin (O')		1	0
Unit cell intercepts	а	b	С
2. Intercept from origin (O')	-1	$\frac{-1}{2}$	1
3. Reciprocal value		-2	1
4. Miller Indices		(1 2 1)	

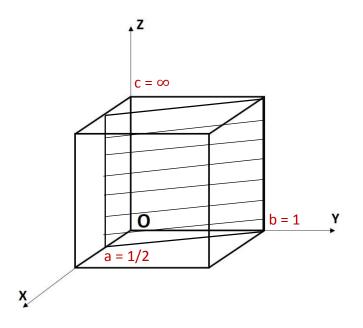


Determine the indices for the given plane.

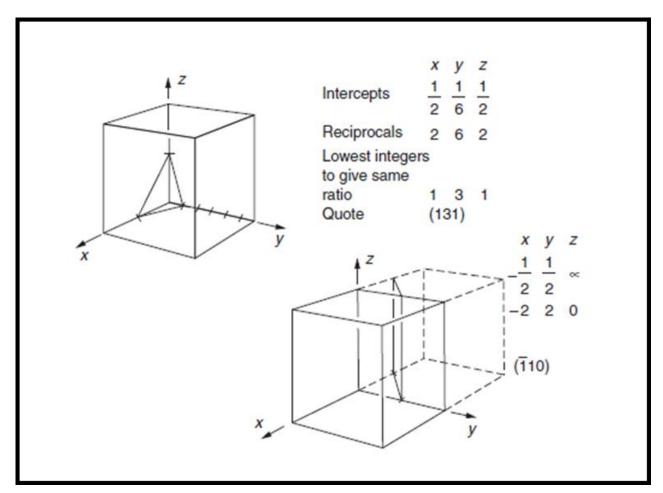
- Plane cannot touch origin
- Choose closest origin

This plane cuts two of the reference axes(X & Y) at intercepts a & b

1.Choose Origin (O)	0	0	0
Unit cell intercepts	а	b	С
2. Intercept from origin (O)	$\frac{1}{2}$	1	∞
3. Reciprocal value	2	1	0
4. Miller Indices (2 1 0)			



Miller indices – more examples (given plane)

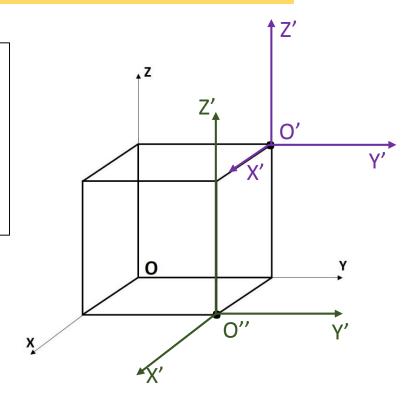


Selecting the Origin – Indices with bar

- If there is a bar over the number (x, y or z), the new origin O' should have a '1' in the same place as number with a bar.
- If there is not a bar over the number, the new origin O' should have zero 'O' in the same place as the non-bar number.

Number with bar, then replace \overline{N} = 1 If no bar over the number, then N = 0

Indices	New Origin	
(0 1 2)	X = 0, Y = 0, Z = 0 (No change)	
$(0 \overline{1} \overline{1})$	X'= 0, Y'= 1, Z'= 1	
$(\overline{1}\overline{2}2)$	X''= 1, Y''= 1, Z''= 0	



Given Indices (h k l) > **Draw the Plane**

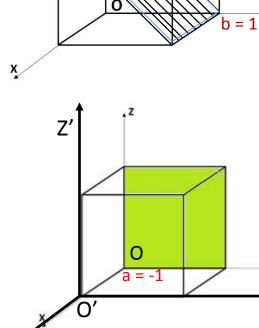
- Select origin O at (0,0,0) OR if there are negative indices then origin at O' in X', Y', Z' frame.
- Take reciprocal of indices to get 1/h, 1/k, 1/l: which will be the intercept.
- Mark intercept along x, y, z axes at a, b, c.
- Draw plane by connecting intercepts (a, b, c).

Given Indices (0 1 1) > **Draw the Plane**

1.Choose Origin (O)	0	0	0
2. Reciprocal value of indices (0 1 1)	∞ (parallel to x-axis)	1	1
Unit cell intercept	а	b	С
3. Mark & connect intercepts	Draw Plane		

Given Indices $(\bar{1}\ 0\ 0)$ > Draw the Plane

1.Choose Origin (O')	1	0	0
2. Reciprocal value of indices ($\overline{1}$ 0 0)	-1	∞ (parallel to Y-axis)	∞ (parallel to Z-axis)
Unit cell intercept	а	b	С
3. Mark & connect intercepts	Draw Plane		



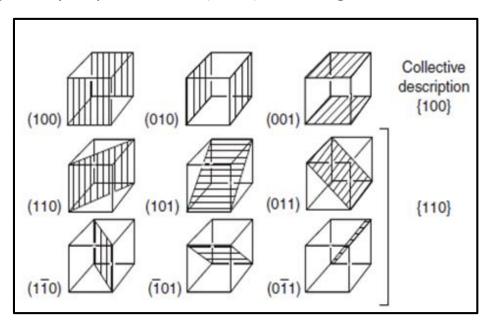
c = 1



Families of plane – are "Equivalent"

- Different planes having same index in their miller indices (not necessarily in same order) is shown by Miller indices of family of planes.
- ✓ Same Packing density
- ✓ Same environment
- ✓ Denoted by curly bracket {H K L}

For cubic system, indices of a family of plane is given by all permutation(+ & -) of 3 integer indices.



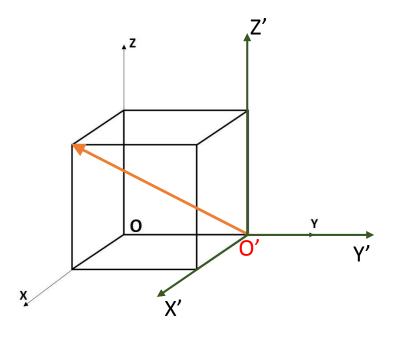
Reference: Engineering Materials 1: Ashby & Jones, 4th Ed.

How to find Miller Indices of a given direction?

Given direction > determine **indices** [???].

- Create new origin O' at tail, if necessary.
- Label O' and new axes X', Y' & Z'.
- Find coordinates from tail at O' to the head of direction.
- Reduce multiples, eliminate fractions, use 'bar' for negative.
- Place square bracket "[]" around integer.

Ans : $[1\overline{1}1]$

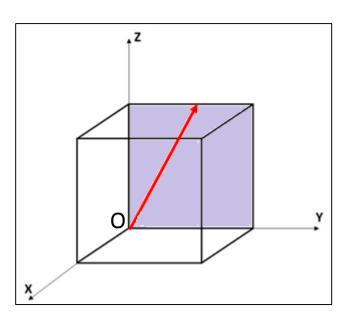


Drawing directions from Indices

Example

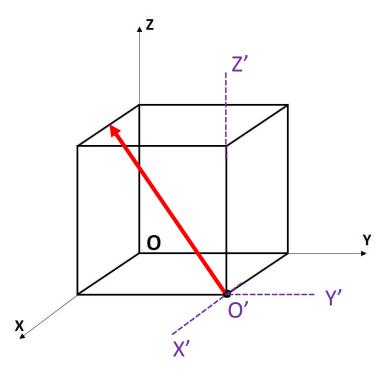
Given indices [0 1 2] > draw direction.

- **Select** origin O at (0,0,0) <u>OR</u> choose new O' if there are negative indices.
- Reduce indices to keep direction within unit cell (in this case divide by 2).
- Locate from origin at (0,0,0) to a position $(0, \frac{1}{2}, 1)$ in the unit cell.
- Draw direction from tail (0,0,0) to arrow tip at (0, ½,1)



Draw the **specified direction** in the unit cell with **indices given** as $[\overline{1}\ \overline{2}\ 2]$.

- Select new origin O' as (1,1,0)
- Reduce $[\overline{1}\ \overline{2}\ 2]$ to -1/2, -1, 1 with in the unit cell
- Locate the coordinates.
- Draw direction from origin to the coordinates.



Unit Cell families of Direction

• Composed of unique unit cell direction that are "equivalent".

• In cubic system members of a family are given by all possible permutation of indices.

• Same properties, packing densities, same environment, etc.

Denoted by integers in a "Carrot Bracket", <U V W>

Example : Specify all unique direction in family <1 1 1>

<1 1 1>: [1 1 1], [$\overline{1}$ 1 1], [1 1 $\overline{1}$], [1 $\overline{1}$ 1] called **Body Diagonals**.



Identify and draw unit cell families of direction

Find all of the unique direction for the given family. Find all the indices, draw the direction and give the name of the family?

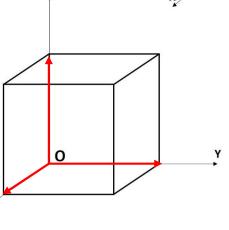
A) <1 10> = [1 10], [
$$\overline{1}$$
 10], [$\overline{1}$ 0 1], [1 0 1], [0 1 1], [0 $\overline{1}$ 1]

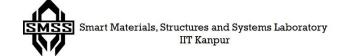
Face diagonals

(parallel directions are not unique)



Cube Edges





Always remember

What do the different brackets mean?

Name	Symbol	Meaning
Half-moon	()	Individual Plane
Bracket	\ /	(100)
Curly	()	Family of Planes
Bracket	{ }	$\{1\ 0\ 0\} = (1\ 0\ 0), (0\ 1\ 0), (0\ 0\ 1)$
Square	ГЭ	Individual direction
bracket	l J	[100]
Carrot		Family of Directions
Bracket	< >	<1 0 0> = [1 0 0], [0 1 0], [0 0 1]

Properties of Miller Indices

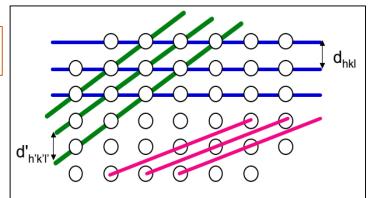
- Miller indices of equally spaced parallel planes are the same.
- Miller indices of a plane passing through the origin is shown by a miller indices of a plane parallel to it.
- If two planes having miller indices as $(h_1 k_1 l_1)$ and $(h_2 k_2 l_2)$ are **perpendicular** to each other. then, $h_1h_2 + k_1k_2 + l_1l_2 = 0$
- All members of family of planes or directions are not necessarily parallel to one another.

Inter Planer Spacing (dhkl)

- Distances between planes defined by the same set of Miller indices.
- Members of family of planes have the same inter planer spacing.

Inter planer spacing (cubic only),
$$d_{hkl} = \frac{(cube\ side\ length)}{\sqrt{h^2 + k^2 + l^2}}$$

Inter planer angle (**cubic only**),
$$\cos \theta = \frac{h_1 h_2 + k_1 k_2 + l_1 l_2}{\sqrt{h_1^2 + k_1^2 + l_1^2} \sqrt{h_2^2 + k_2^2 + l_2^2}}$$





Planar density

Planar density , PD =
$$\frac{\text{No. of effective atoms per unit area}}{\text{Area of plane}}$$

Planar density of (110) plane in the FCC crystal

No. of effective atoms per unit area = $\frac{1}{4}$ x 4 corner atoms + $\frac{1}{2}$ x 2 side atoms = 2

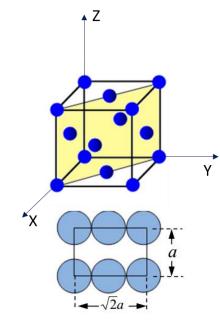
$$PD_{(110)} = \frac{2}{a\sqrt{2}a} = \frac{\sqrt{2}}{a^2}$$

Planar density of (111) plane in the FCC crystal

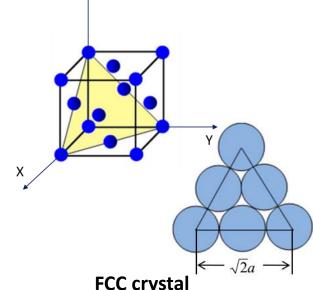
No. of effective atoms per unit area = $\frac{1}{6}$ x 3 corner atoms + $\frac{1}{2}$ x 3 side atoms = 2

$$PD_{(111)} = \frac{2}{\frac{1}{2}(base \times height)} = \frac{4}{\sqrt{3}a^2}$$

This is higher than [110] and any other plane. Therefore, (111) plane is the most densely packed plane in the FCC crystal



FCC crystal





Linear density

Linear density ,
$$LD = \frac{\text{No. of effective atoms on a line}}{\text{Length of direction vector}}$$

Linear density in [110] direction in the FCC crystal

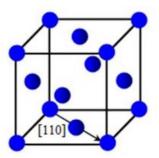
$$LD_{[110]} = \frac{\text{No. of effective atoms on a line}}{\text{Length of direction vector}} = \frac{\frac{1}{2} + 1 + \frac{1}{2}}{\sqrt{2} \text{ a}} = \frac{2}{\sqrt{2} \text{ a}}$$

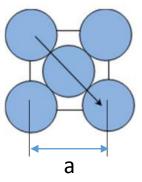
This is the most densely packed direction in the FCC lattice.



Highest atomic density plane: (110)

Highest atomic density direction: [111]





FCC crystal

- ✓ Deformation in metals depends on linear and planar density.
- ✓ Slip occurs on most densely packed crystallographic planes and along directions having the greatest atomic packing due to lower shear stress/energy requirement.

The Role of Crystal Structure – III

(Crystal defects)

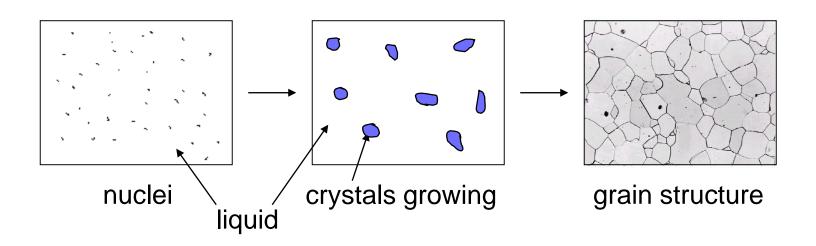
Contents

Crystal Defects

- **✓** Introduction
- **✓ Point defects**
- ✓ Line defects
- ✓ Plane defects
- ✓ Volume defects

Solidification

- Result of casting of molten material.
 - 2 steps
 - ✓ Nucleation (site of new thermodynamic phase)
 - ✓ Nuclei grow to form crystals grain structure
 - > Start with a molten material all liquid.
 - > Crystals grow until they meet each other.



Crystal Defects

- Any **deviation** from completely **ordered arrangement** of constituent particles in a crystal is called a "**Defect or Imperfection**".
- Properties of material are influenced by the presence of imperfections.
- Mechanical properties of pure metal change significantly when metals are alloyed.

Yield strength of **Pure Copper** (Cu): 117 MPa Yield strength of **Brass** (70% Cu + 30% Zinc): 200 MPa

• Thus, it is important to have knowledge about the types of imperfections that exist and the roles they play in affecting the behavior of materials.

Classification

Based on shape and size of defects:

- Point defects (zero dimensional)
 - √ Vacancy defect
 - ✓ Interstitial defect
 - ✓ Substitutional defect
 - ✓ Frenkel defect.
 - ✓ Schottky defect
- Line defects / Dislocations (One dimensional)
 - ✓ Edge dislocation
 - ✓ Screw dislocation
 - ✓ Mixed dislocation
- Plane defects (Two dimensional)
 - ✓ Grain boundaries
 - ✓ Twin boundaries
- Volume defects (Three dimensional)
 - ✓ Pores
 - ✓ Cracks, etc.

Extended defects

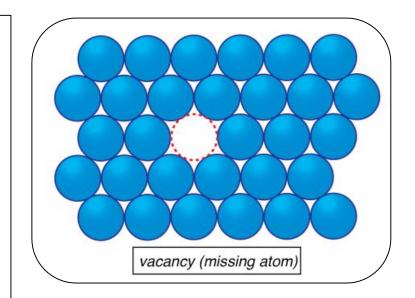


Point defects

(associated with atomic sites)

Vacancy defect

- When an atom is missing from its regular lattice site, it is called a Vacancy.
- Impossible to create a material free from vacancy defects.
- Presence of vacancies increases the entropy/disorderness in the crystal.
- Decreases the density of substance.
- The concentration of vacancies increases with
 - Increasing temperature.
 - \triangleright Decreasing activation energy (Q_v) energy required for the formation of vacancies



No. of vacancies,
$$Nv = N \exp\left(\frac{-Q_v}{kT}\right)$$

Where, **N** is the total no. of potential defect sites (each lattice site is potential defect site), $\mathbf{Q}_{\mathbf{v}}$ is the activation energy , **k** is Boltzmann constant = 1.38×10^{-23} J/atom-K or 8.62×10^{-5} eV/atom-K

T is absolute temperature in Kelvin

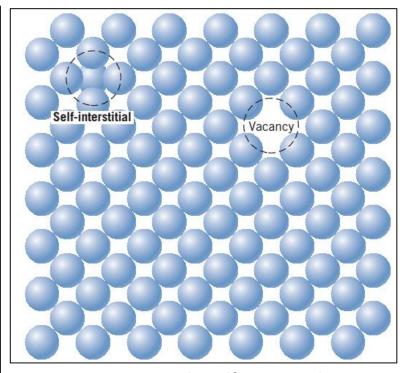


Self-interstitial defect

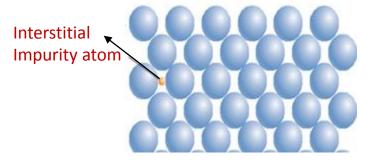
- Atom from the crystal occupies a position in between the atomic sites called as self-interstitial defect.
- Vacancies and Self-Interstitial are inverse phenomenon.
- In metals, it introduces relatively large distortions (strain) in the surrounding lattice since the atom is substantially larger than the interstitial site.
- When a foreign atom occupies an interstitial site called an Interstitial defect.
- **Interstitial defect** increases the density of the substance.

Example:

- ✓ Carbon forms an interstitial solid solution when added to iron.
- ✓ The atomic radius of the carbon (0.071 nm) atom is much less than that for iron (0.124 nm)



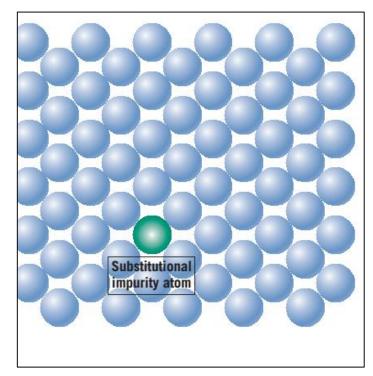
Vacancy and a self-interstitial





Substitutional defect

- A Substitutional defect is introduced when one atom replaced by a different type of atom.
- **Crystal structures** of both atom types must be the **same** and almost equal electronegativity's.
- The substitutional atom occupy the normal lattice site.
- The substitutional defects can be introduced either as an impurity or as alloy addition.
- **Example**: Cu (0.128 nm) & Ni (0.125 nm) form substitutional solid solution (both FCC) and are completely soluble at all proportions.

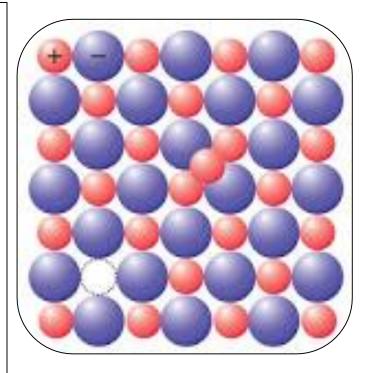


Substitutional defect



Frenkel defect

- It is a combination of Vacancy and Interstitial defect.
- Occurs when an atom or ion leaves its regular site and occupies an interstitial site, it is known as Frenkel defect.
- Cations being smaller in size gets displaced to interstitial voids.
- No change in the density occurs.
- Found in ionic compounds with low coordination numbers.
- Example : AgI, CaF₂

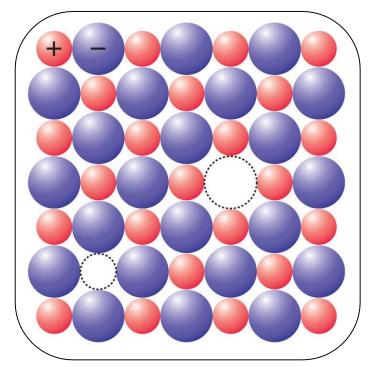


Frenkel defect

Schottky defect

- Associated with a paired set of cation and anion vacancies.
- Density of the solid decreases.
- Found in ionic compounds with high coordination numbers.
- In order to maintain electrical neutrality, the number of **missing cations** and **anions** are **equal**.
- Example : Alkali halides such as NaCl, KF, etc.

In both Frenkel and Schottky - No change in electrical neutrality of the crystal



Schottky defect